INFORMATION DISCLOSURE STATEMENT BY APPLICANT (use as many sheets as necessary)						Complete if Known Application Number Filing Date First Named Inventor Group Art Unit		10/656,578 September 4, 2003 Pavel I. LAZAREV		
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	<u>L</u>						Docket Number	A-71	760/AJT/TJH 031-139)	
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Unique citation designation number. ¹ See attached Kinds of U.S. Patent Documents. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial possible, ⁶ Applicant is to place a check mark here if English Language Translation is attached.

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